

T-79-06-20

# IR94558/IR94558N/IR94559/IR94559N

## Low Noise Dual Operational Amplifier

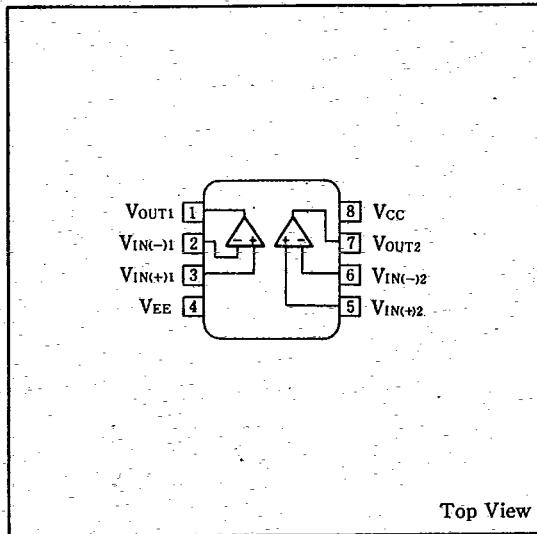
### Description

The IR94558/IR94558N and IR94559/IR94559N are low noise dual operational amplifiers. High input resistance, wide common mode input voltage range, and absence of latch-up make these amplifiers ideal for voltage-follower applications.

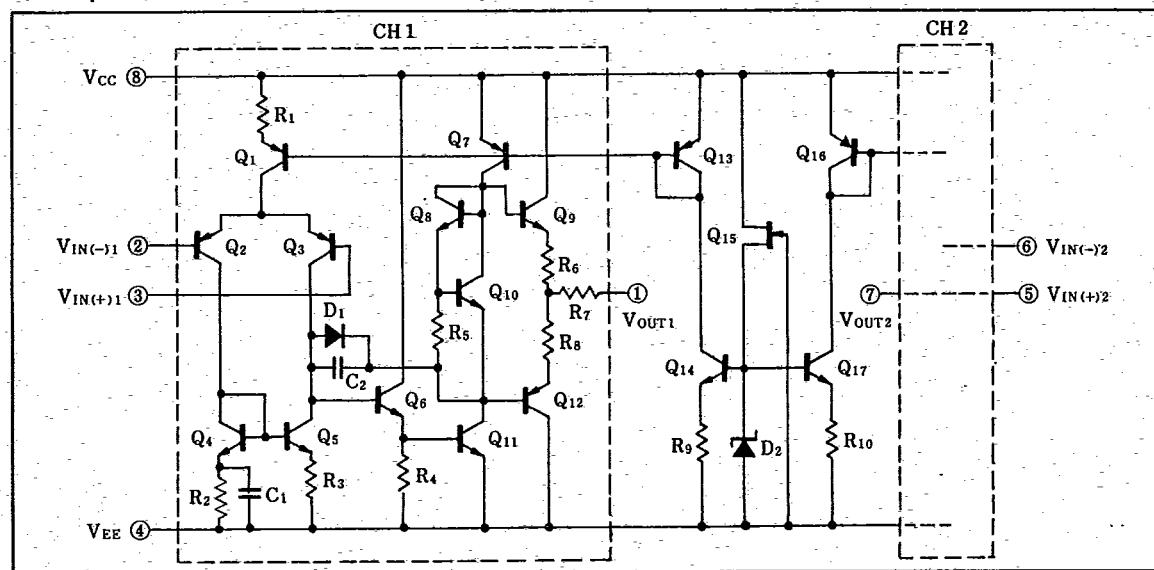
### Features

1. No frequency compensation required
2. High input impedance  $5M\Omega$  (TYP.)
3. Short circuit protected outputs
4. 8-pin dual-in-line package (IR94558/IR94559)
5. 8-pin small-outline package (IR94558N/IR94559N)

### Pin Connections



### Equivalent Circuit

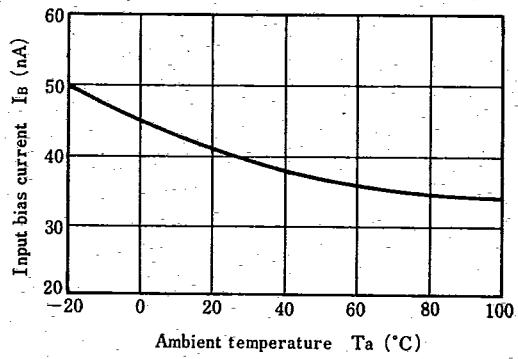
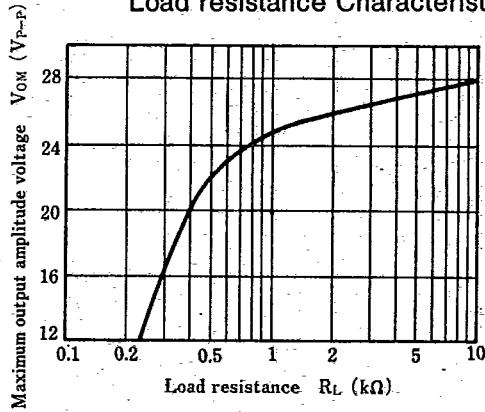


**Absolute Maximum Ratings**
 $(T_a = 25^\circ\text{C})$ 

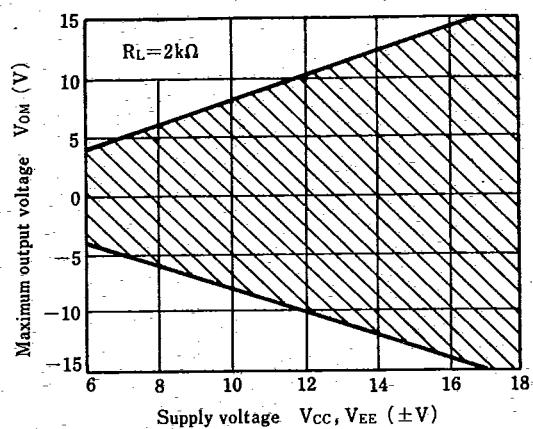
Parameter	Symbol	Condition		Rating	Unit
Supply voltage	$V_{CC} - V_{EE}$			36	V
Differential input voltage	$V_{ID}$			$\pm 30$	V
In-phase input voltage <sup>*1</sup>	$V_{ICM}$			$\pm 15$	V
Power dissipation	$P_D$	$T_a \leq 25^\circ\text{C}$	IR94558/IR94559	500	mW
			IR94558N/IR94559N	500	
$P_D$ derating ratio	$\Delta P_D/\text{ }^\circ\text{C}$	$T_a > 25^\circ\text{C}$	IR94558/IR94559	5	mW/ $^\circ\text{C}$
			IR94558N/IR94559N	4	
Operating temperature	$T_{opr}$			-20 ~ +75	$^\circ\text{C}$
Storage temperature	$T_{stg}$			-55 ~ +150	$^\circ\text{C}$

**Electrical Characteristics**
 $(V_{CC} = 15\text{V}, V_{EE} = -15\text{V}, T_a = 25^\circ\text{C})$ 

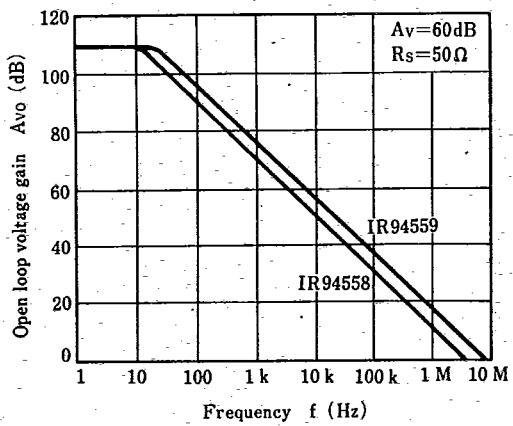
Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Input offset voltage	$V_{IO}$	$R_S \leq 10\text{k}\Omega$		0.5	6	mV
Input offset current	$I_{IO}$			5	200	nA
Input bias current	$I_B$			40	500	nA
Input impedance	$Z_{IN}$		0.3	5		$\text{M}\Omega$
In-phase input voltage	$V_{ICM}$		$\pm 12$	$\pm 14$		V
Major amplitude voltage gain	$A_V$	$R_L \geq 2\text{k}\Omega, V_{OUT} = \pm 10\text{V}$	86	110		dB
Maximum output voltage	$V_{OM}$	$R_L \geq 10\text{k}\Omega$	$\pm 12$	$\pm 14$		V
		$R_L \geq 2\text{k}\Omega$	$\pm 10$	$\pm 13$		
Common signal rejection ratio	CMR	$R_S \leq 10\text{k}\Omega$	70	90		dB
Supply voltage rejection ratio	SVR	$R_S \leq 10\text{k}\Omega$		30	150	$\mu\text{V/V}$
Power dissipation	$P_D$			105	170	mW
Input conversion noise voltage	$V_{NI}$	$R_S = 1\text{k}\Omega, BW = 10\text{Hz} \sim 30\text{kHz}$	2.5			$\mu\text{V}_{rms}$
Gain band product	G.B.	$R_L = 2\text{k}\Omega$	IR94558/IR94558N	3.0		MHz
			IR94559/IR94559N	6.0		
Slew rate	SR	$R_L \geq 2\text{k}\Omega$	IR94558/IR94558N	1.0		$\text{V}/\mu\text{s}$
			IR94559/IR94559N	2.0		

**Electrical Characteristic Curves (Unless otherwise specified,  $V_{CC} = 15\text{V}, V_{EE} = -15\text{V}, T_a = 25^\circ\text{C}$ )**
**Input bias current—Ambient temperature  
Characteristics**

**Maximum output amplitude voltage—  
Load resistance Characteristics**


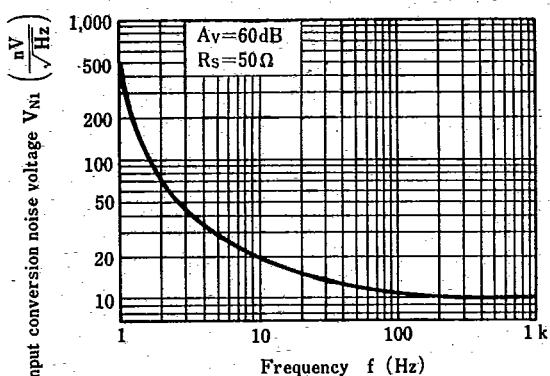
Maximum output voltage—Supply voltage  
Characteristics



Open loop voltage gain—Frequency  
Characteristics



Input conversion noise voltage—  
Frequency Characteristics



3

Maximum output amplitude voltage—  
Frequency Characteristics

